

# **Small Signal Schottky Barrier Diode**

## SD103AW SD103BW SD103CW

- Low reverse current and low forward
- voltage.
- High reliability.
- Small surface mounting type.



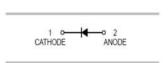


# **Typical Applications**

For general purpose applications

### **Mechanical Data**

- Case: SOD-123
- Molding compound, UL flammability classification rating 94V-0.
- Terminals: Tin plated leads, solderable per MIL-STD-202, Method 208.





**SOD-123** 

# **Ordering Information**

Part Number	Package	Shipping	Marking Code
SD103AW□	SOD-123	3000/Tape Reel	S4
SD103BW□	SOD-123	3000/Tape Reel	<b>S</b> 5
SD103CW□	SOD-123	3000/Tape Reel	S6

<sup>☐:</sup> none is for Lead Free package;

# Maximum Ratings (@T<sub>A</sub>=25℃ unless otherwise specified)

Characteristic	Symbol	SD103AW	SD103BW	SD103CW	Units
Peak repetitive reverse voltage	$V_{RRM}$	40	30	20	V
RMS Reverse voltage	V <sub>RMS</sub>	28	21	14	V
Maximum average forward output current	I <sub>F(AV)</sub>		350		mA
Peak forward surge current,8.3ms single half-sine-wave	I <sub>FSM</sub>	1.5		Α	

### **Thermal Characteristics**

Characteristic	Symbol	Value	Units
Power dissipation	P <sub>D</sub>	400	mW
Typical thermal resistance per leg	R <sub>⊝JA</sub> *	300	°C/W
Operating junction temperature range	TJ	125	°C
Storage temperature range	T <sub>STG</sub>	-55 to +150	°C

\* Part mounted on FR-4 board with recommended pad layout

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<sup>&</sup>quot;G" is for Halogen Free package.

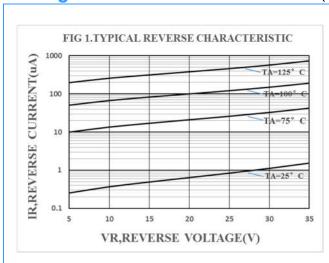
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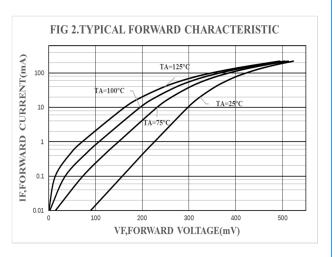
# Electrical Characteristics (@TA=25°C unless otherwise specified)

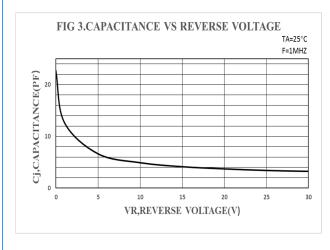
, •					
Symbol	Test conditions	Min.	Тур.	Max.	Units
V <sub>F</sub> *	I <sub>F</sub> =20mA	-	-	0.37	V
	I <sub>F</sub> =200mA	-	-	0.60	
l <sub>R</sub> **	V <sub>R</sub> = 30V (SD103AW)				
	V <sub>R</sub> = 20V (SD103BW)	-	-	5	uA
	V <sub>R</sub> = 10V (SD103CW)				
Ст	V <sub>R</sub> =0V,f=1MHz	-	22	50	pF
	V <sub>F</sub> *	$V_{F}^{*} = I_{F}=20 \text{mA}$ $I_{F}=200 \text{mA}$ $V_{R}=30 \text{V (SD103AW)}$ $V_{R}=20 \text{V (SD103BW)}$ $V_{R}=10 \text{V (SD103CW)}$	$V_{F}^{*} = I_{F} = 20 \text{mA} - I_{F} = 200 \text{mA} - I_{F} = 200 \text{mA} - I_{F} = 30 \text{V (SD103AW)} - I_{R}^{**} = 20 \text{V (SD103BW)} - I_{R}^{**} = 10 \text{V (SD103CW)}$	I <sub>F</sub> =20mA	VF*       IF=20mA       -       -       0.37         IF=200mA       -       -       0.60         VR= 30V (SD103AW)       -       -       5         VR= 20V (SD103BW)       -       -       5         VR= 10V (SD103CW)       -       -       5

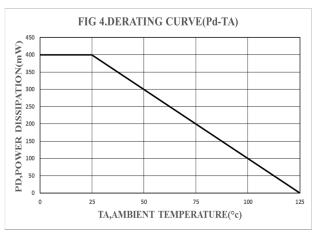
<sup>\*</sup>Pulse width ≤380 uS, Duty cycle < 2%

## Ratings and Characteristic Curves (T<sub>A</sub>=25°C unless otherwise noted)









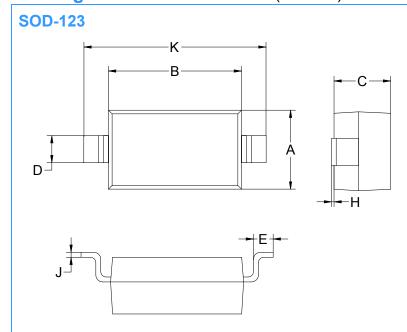
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<sup>\*\*</sup>pulse test , tp≤5ms



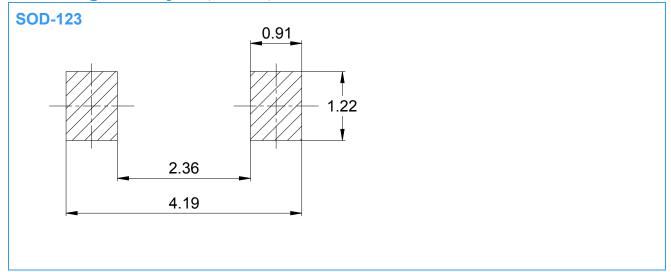
# Small Signal Schottky Barrier Diode SD103AW SD103BW SD103CW

# Package Outline Dimensions(unit:mm)



SOD-123				
Dim	Min	Max		
Α	1.45	1.75		
В	2.55	2.85		
С	1.00	1.30		
D	0.50	0.60		
E	0.25	0.45		
Н	0.02	0.10		
J	0.05	0.15		
K	3.55	3.85		

# **Mounting Pad Layout**(unit:mm)



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